

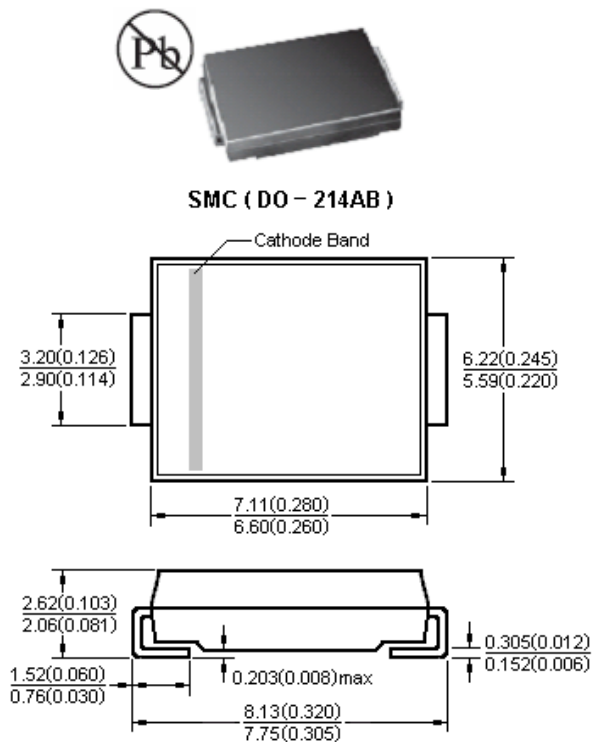


Features

- Glass passivated chip junctions
- Ideal for automated placement
- Ultrafast reverse recovery time for high efficiency
- Low profile package
- High forward surge capability
- High temperature soldering: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/1 and WEEE 2002/96/EC

Mechanical Date

- **Case:** JEDEC DO-214AB molded plastic body over passivated chip
- **Terminals:** Solder plated, solderable per J-STD-002B and JESD22-B102D
- **Polarity:** Laser band denotes cathode end



Dimensions in millimeters and (inches)

Maximum Ratings and Electrical Characteristics Rating at 25 °C

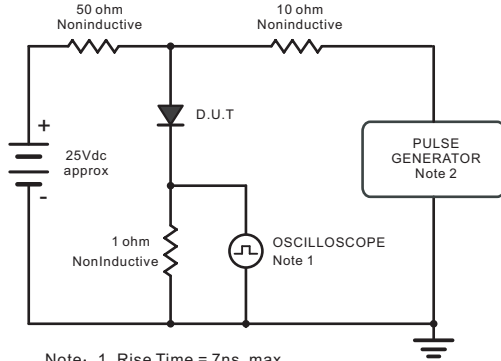
ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Parameter	Symbols	ES3K	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	800	V
Maximum RMS voltage	V_{RMS}	560	V
Maximum DC Blocking Voltage	V_{DC}	800	V
Maximum Average Forward Rectified Current at $T_c = 125\text{ }^\circ\text{C}$	$I_{F(AV)}$	3	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	90	A
Maximum Forward Voltage at 3 A	V_F	1.7	V
Maximum DC Reverse Current $T_a = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125\text{ }^\circ\text{C}$	I_R	5 100	μA
Typical Junction Capacitance at $V_R=4\text{V}$, $f=1\text{MHz}$	C_j	40	pF
Maximum Reverse Recovery Time ⁽¹⁾	t_{rr}	35	ns
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$ $R_{\theta JC}$	40 16	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150	$^\circ\text{C}$

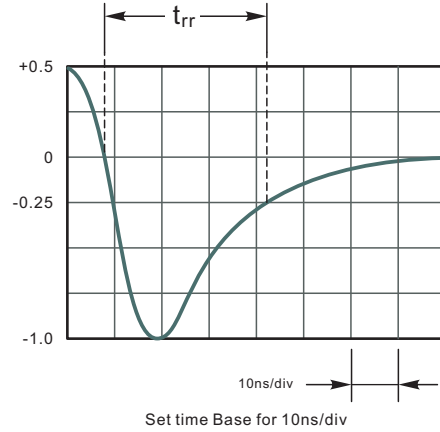
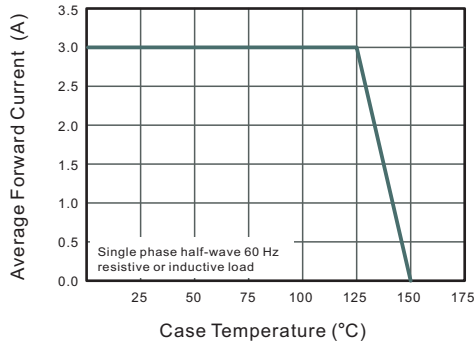
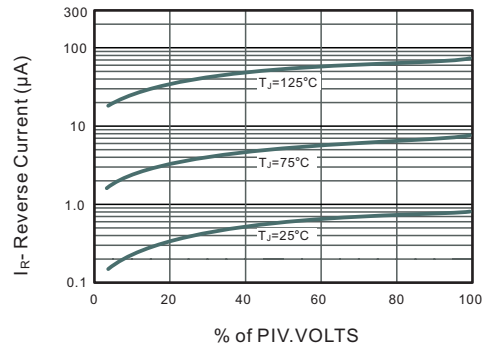
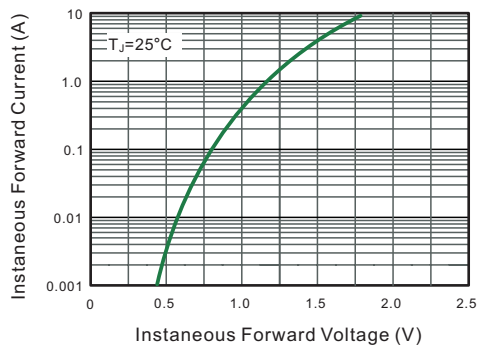
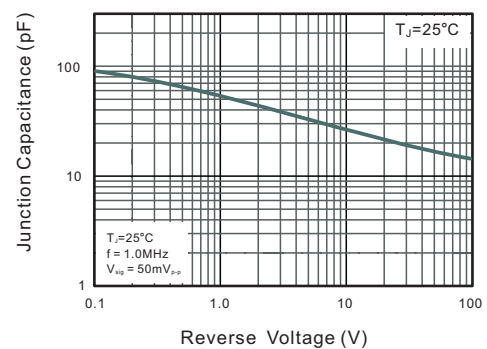
(1) Measured with $I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$.

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)
Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram


Note: 1. Rise Time = 7ns, max.
Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns, max.
Source Impedance = 50 ohms.


Fig.2 Maximum Average Forward Current Rating

Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics

Fig.5 Typical Junction Capacitance

Fig.6 Maximum Non-Repetitive Peak Forward Surge Current
